

# 600mA 8kV -High Voltage Power Diodes

High reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

### Features

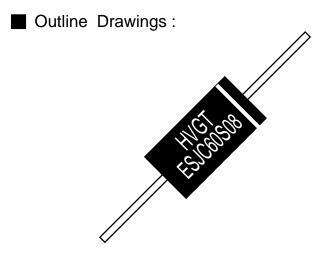
- High speed switching
- Epoxy resin molded in vacuum, Have anticorrosion in the surface
- High surge resisitivity for CRT discharge
- High reliability design
- Avalanche characteristic

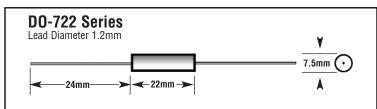
### **Applications**

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power
- General purpose high voltage rectifier, Voltage multiplier assembly.

## Maximum Ratings and Characteristics

Absolute Maximum Ratings





Items	Symbols	Condition	ESJC60S08	Units
Repetitive Peak Renerse Voltage	$V_{RRM}$	Ta=25°C, IR =0.1mA	8.0	kV
Average Output Current	lo	Ta=25°C,Resistive Load	0.6	A peak
Suege Current	I <sub>FSM</sub>	Ta=25°C,8.3msec, half sine	30	A peak
Junction Temperature	Tj		125	°C
Allowable Operation Case Temperature	Тс		125	°C
Storage Temperature	Tstg		-40 to +125	°C

#### • Electrical Characteristics (Ta=25°C Unless otherwise specified)

Items	Symbols	Conditions	ESJC60S08	Units
Maximum Forward Voltage Drop	VF	at 25°C, at: I <sub>F</sub>	10	V
Maximum Reverse Current	IR1	at 25°C,VR =VRRM	5.0	uA
	IR2	at 100°C,VR =VRRM	50	uA
Maximum Reverse Recovery Time	Trr	at 25°C;   F = 0.5 R;   R =   F(AV);     Irr = 0.25 R		nS
Junction Capacitance	Cj	at 25°C;V <sub>R</sub> =0V,f=1MHz		pF